

PJT7801-AU

20V P-Channel Enhancement Mode Mosfet – ESD Protected

Voltage

-20 V

Current

-0.7A

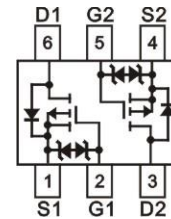
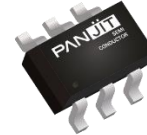
Features

- $R_{DS(ON)}$, $V_{GS}@-4.5V$, $I_D@-0.7A < 325m\Omega$
- $R_{DS(ON)}$, $V_{GS}@-2.5V$, $I_D@-0.6A < 420m\Omega$
- $R_{DS(ON)}$, $V_{GS}@-1.8V$, $I_D@-0.5A < 600m\Omega$
- Advanced Trench Process Technology
- ESD Protected 2KV HBM
- Specially Designed for Switch Load, PWM Application, etc.
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : SOT-363 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.006 grams

SOT-363



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ C$ unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS	
Drain-Source Voltage	V_{DS}	-20	V	
Gate-Source Voltage	V_{GS}	± 8	V	
Continuous Drain Current ^(Note 4)	I_D	-0.7	A	
Pulsed Drain Current ^(Note 1)	I_{DM}	-2.8	A	
Power Dissipation	P_D	$T_a=25^\circ C$	350	mW
		Derate above $25^\circ C$	2.8	mW/ $^\circ C$
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55~150	$^\circ C$	
Thermal Resistance	$R_{\theta JA}$	357	$^\circ C/W$	
- Junction to Ambient ^(Note 3)				

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Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-20	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250uA	-0.5	-0.64	-1.0	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-4.5V, I _D =-0.7A	-	260	325	mΩ
		V _{GS} =-2.5V, I _D =-0.6A	-	310	420	
		V _{GS} =-1.8V, I _D =-0.5A	-	400	600	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-20V, V _{GS} =0V	-	-	-1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±8V, V _{DS} =0V	-	-	±10	uA
Dynamic (Note 5)						
Total Gate Charge	Q _g	V _{DS} =-10V, I _D =-0.7A, V _{GS} =-4.5V (Note 2)	-	2.2	-	nC
Gate-Source Charge	Q _{gs}		-	0.4	-	
Gate-Drain Charge	Q _{gd}		-	0.5	-	
Input Capacitance	C _{iss}	V _{DS} =-10V, V _{GS} =0V, f=1.0MHZ	-	165	-	pF
Output Capacitance	C _{oss}		-	25	-	
Reverse Transfer Capacitance	C _{rss}		-	14.7	-	
Turn-On Delay Time	t _{d(on)}	V _{DD} =-10V, I _D =-0.7A, V _{GS} =-4.5V, R _G =6Ω (Note 2)	-	8.9	-	ns
Turn-On Rise Time	t _r		-	37	-	
Turn-Off Delay Time	t _{d(off)}		-	127	-	
Turn-Off Fall Time	t _f		-	70	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I _S	---	-	-	-0.7	A
Diode Forward Voltage	V _{SD}	I _S =-1A, V _{GS} =0V	-	-0.86	-1.2	V

NOTES :

1. Pulse width ≤ 300us, Duty cycle ≤ 2%.
2. Essentially independent of operating temperature typical characteristics.
3. R_{θJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
4. The maximum current rating is package limited.
5. Guaranteed by design, not subject to production testing.

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TYPICAL CHARACTERISTIC CURVES

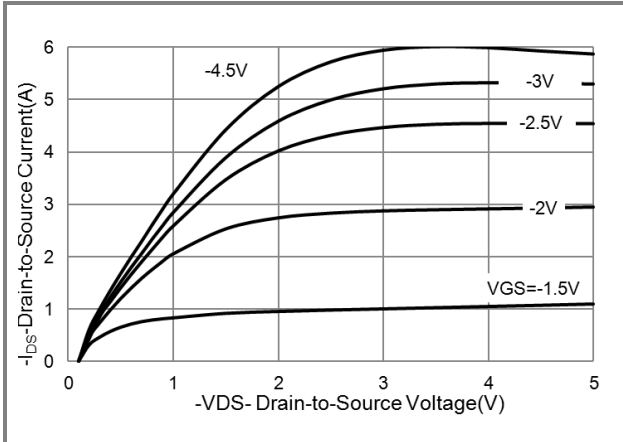


Fig.1 On-Region Characteristics

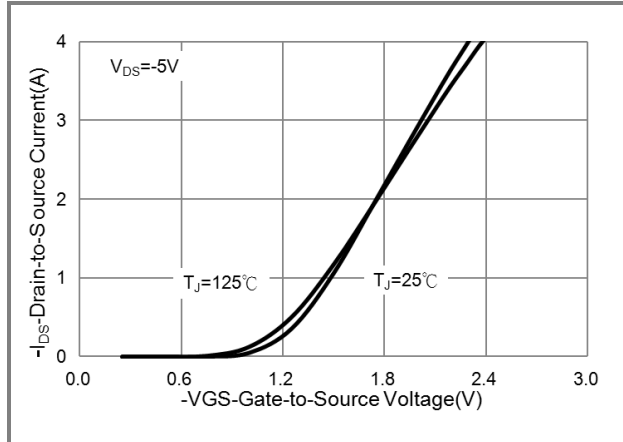


Fig.2 Transfer Characteristics

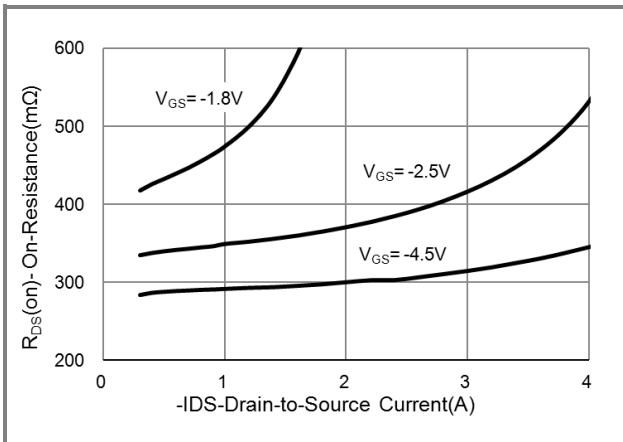


Fig.3 On-Resistance vs. Drain Current

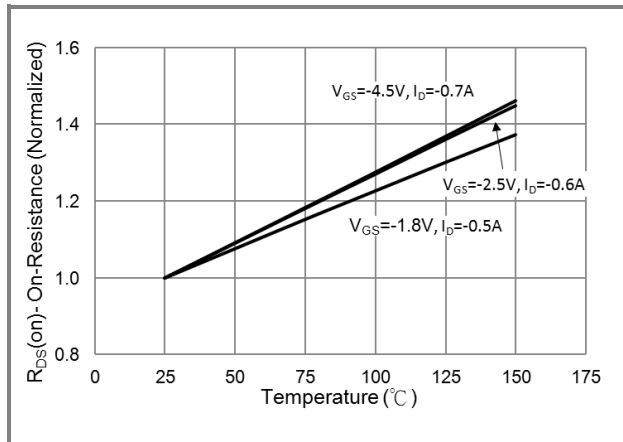


Fig.4 On-Resistance vs. Junction temperature

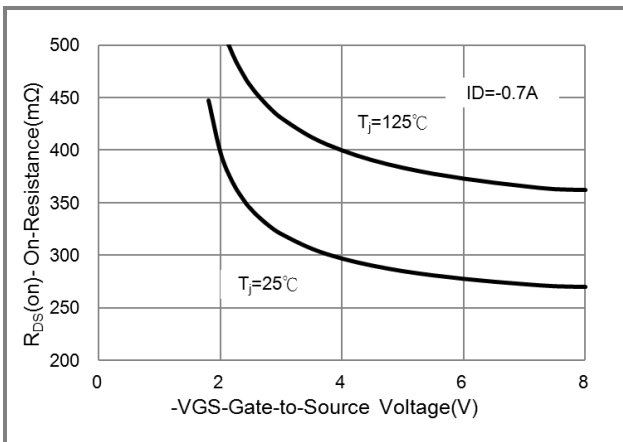


Fig.5 On-Resistance Variation with VGS.

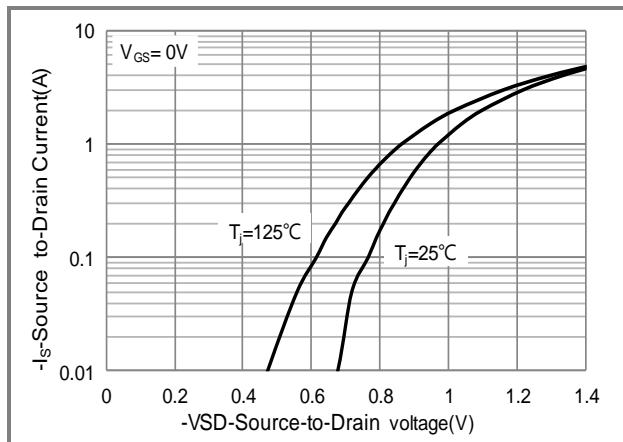


Fig.6 Body Diode Characteristics

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TYPICAL CHARACTERISTIC CURVES

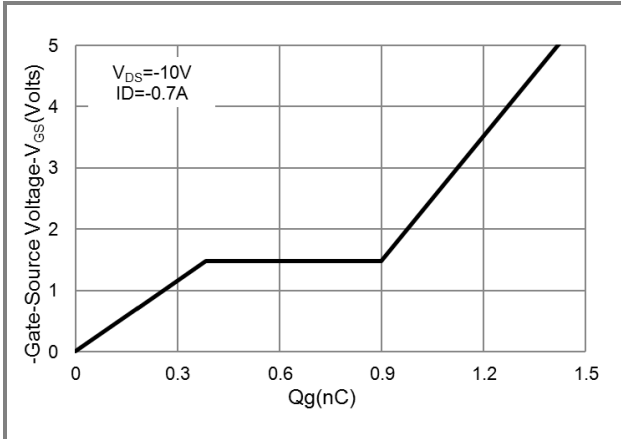


Fig.7 Gate-Charge Characteristics

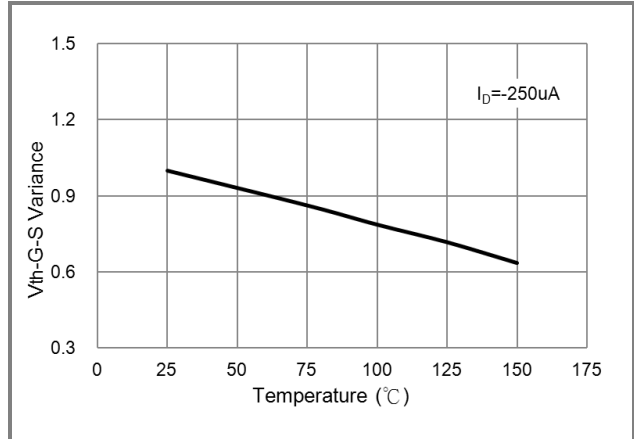


Fig.8 Threshold Voltage Variation with Temperature

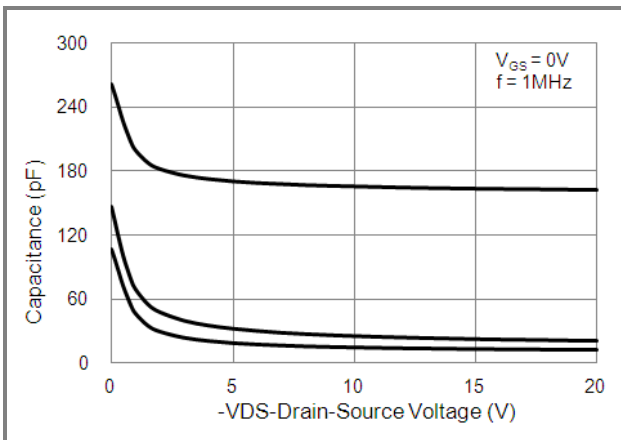


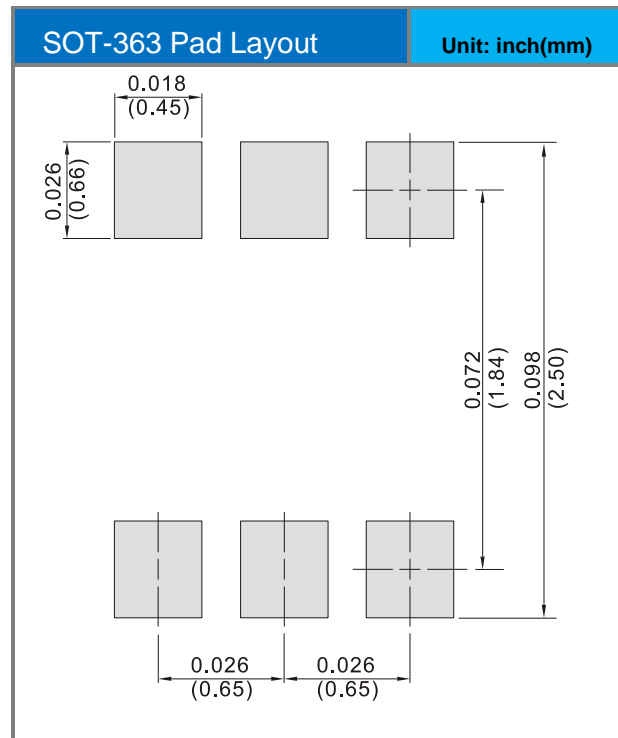
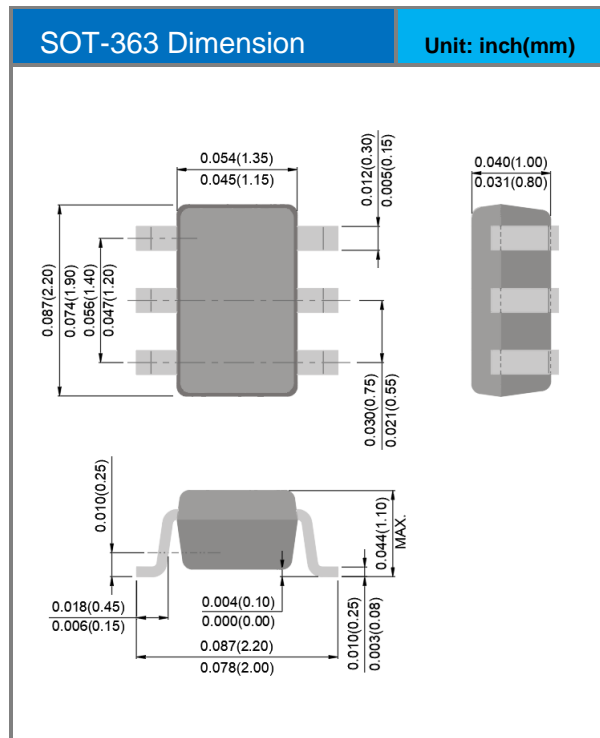
Fig.9 Capacitance vs. Drain-Source Voltage

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Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PJT7801-AU	SOT-363	3K pcs / 7" reel	T01

Packaging Information & Mounting Pad Layout



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